NSN 5961-01-057-6120

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View Online at https://aerobasegroup.com/nsn/5961-01-057-6120 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage, dc and 10.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 120.00 amperes source cutoff current **Power Rating Per Characteristic:** 220.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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